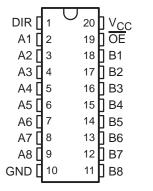
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- Operates From 2.7 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 6.3 ns at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
   >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

## DB, DW, N, NS, OR PW PACKAGE (TOP VIEW)



#### description/ordering information

This octal bus transceiver is designed for 2.7-V to 3.6-V  $V_{CC}$  operation.

The SN74LVCZ245A is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable  $(\overline{OE})$  input can be used to disable the device so the buses are effectively isolated.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

When  $V_{CC}$  is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

#### **ORDERING INFORMATION**

TA	PACK	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
PDIP – N	PDIP – N	Tube of 20	SN74LVCZ245AN	SN74LVCZ245AN		
	SOIC - DW	Tube of 25	SN74LVCZ245ADW	LVCZ245A		
	301C - DW	Reel of 2000	SN74LVCZ245ADWR	LVCZ245A		
4000 to 0500	SOP - NS	Reel of 2000	SN74LVCZ245ANSR	LVCZ245A		
–40°C to 85°C	SSOP – DB	Reel of 2000	SN74LVCZ245ADBR	CV245A		
		Tube of 70	SN74LVCZ245APW	CV245A		
	TSSOP – PW	Reel of 2000	SN74LVCZ245APWR	CV245A		
		Reel of 250	SN74LVCZ245APWT	CV245A		

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



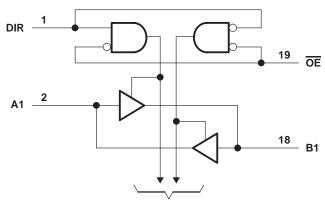
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#### **FUNCTION TABLE**

INP	UTS	OPERATION
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	Isolation

#### logic diagram (positive logic)



To Seven Other Channels

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		
Voltage range applied to any output in the high	-impedance or power-off state, VO	
(see Note 1)		–0.5 V to 6.5 V
Voltage range applied to any output in the high	• • • • • • • • • • • • • • • • • • •	0 5 \/ to \/ + 0 5 \/
(see Notes 1 and 2)		
Input clamp current, $I_{IK}$ ( $V_I < 0$ )		
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)		–50 mA
Continuous output current, IO		±50 mA
Continuous current through V <sub>CC</sub> or GND		±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3)		
,	DW package	
	N package	
	NS package	
	PW package	
Storage temperature range, T <sub>stg</sub>		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
  - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



#### recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
Vcc	Supply voltage		2.7	3.6	V
VIH	High-level input voltage V <sub>CC</sub> = 2.7 V	/ to 3.6 V	2		V
V <sub>IL</sub>	Low-level input voltage V <sub>CC</sub> = 2.7 V	/ to 3.6 V		0.8	V
VI	Input voltage		0	5.5	V
Va	Output veltage		0	VCC	V
۷o	Output voltage 3-state		0	5.5	V
la	$V_{CC} = 2.7 \text{ V}$			-12	mA
ЮН	High-level output current $V_{CC} = 3 \text{ V}$			-24	IIIA
la.	V <sub>CC</sub> = 2.7 V	/		12	A
lOL	Low-level output current $V_{CC} = 3 V$			24	mA
Δt/Δν	Input transition rise or fall rate			6	ns/V
Δt/ΔVCC	Power-up ramp rate		150		μs/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	ARAMETER	TEST CONDIT	IONS	VCC	MIN	TYP <sup>†</sup>	MAX	UNIT
		I <sub>OH</sub> = -100 μA		2.7 V to 3.6 V	V <sub>CC</sub> -0.2			
\/-··		10 mA		2.7 V	2.2			V
VOH		$I_{OH} = -12 \text{ mA}$		3 V	2.4			V
		I <sub>OH</sub> = -24 mA	3 V	2.2				
		I <sub>OL</sub> = 100 μA		2.7 V to 3.6 V			0.2	
VOL		I <sub>OL</sub> = 12 mA	2.7 V			0.4	V	
		I <sub>OL</sub> = 24 mA	3 V			0.55		
ΙĮ	Control inputs	V <sub>I</sub> = 0 to 5.5 V		3.6 V			±5	μΑ
l <sub>off</sub>	-	V <sub>I</sub> or V <sub>O</sub> = 5.5 V		0			±5	μΑ
loz‡		V <sub>O</sub> = 0 to 5.5 V		3.6 V			±5	μΑ
lozpu		$V_O = 0.5 \text{ V to } 2.5 \text{ V},$	OE = don't care	0 to 1.5 V			±5	μΑ
lozpd		$V_0 = 0.5 \text{ V to } 2.5 \text{ V},$	OE = don't care	1.5 V to 0			±5	μΑ
		V <sub>I</sub> = V <sub>CC</sub> or GND		2.6.1/			100	
Icc		3.6 V ≤ V <sub>I</sub> ≤ 5.5 V§	IO = 0	3.6 V			100	μΑ
∆lcc		One input at V <sub>CC</sub> – 0.6 V, Other	inputs at V <sub>CC</sub> or GND	2.7 V to 3.6 V			100	μΑ
Ci	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		4		pF
Cio	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		6		pF



<sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. ‡ For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

<sup>§</sup> This applies in the disabled state only.

## SN74LVCZ245A OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

SCES275G - JUNE 1999 - REVISED AUGUST 2003

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

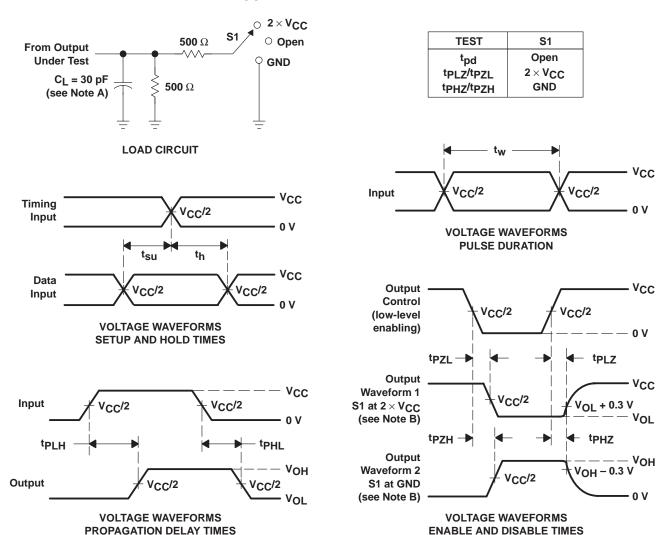
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 2.7 V	V <sub>CC</sub> =	3.3 V 3 V	UNIT
	(1141 01)	(0011 01)	MIN MAX	MIN	MAX	
<sup>t</sup> pd	A or B	B or A	7.3	1.5	6.3	ns
t <sub>en</sub>	ŌĒ	A or B	9.5	1.5	8.5	ns
<sup>t</sup> dis	ŌĒ	A or B	8.5	1.7	7.5	ns

## operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 3.3 V TYP	UNIT
Card	Power discipation conscitance per transceiver	Outputs enabled	f = 10 MHz	42	pF
Cpd	Power dissipation capacitance per transceiver	Outputs disabled	I = IO WIHZ	3	pΓ



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



- NOTES: A. C<sub>I</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpl 7 and tpH7 are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







10-Dec-2020

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LVCZ245ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A	Samples
SN74LVCZ245ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ245A	Samples
SN74LVCZ245ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ245A	Samples
SN74LVCZ245APW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A	Samples
SN74LVCZ245APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A	Samples
SN74LVCZ245APWT	ACTIVE	TSSOP	PW	20	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



### **PACKAGE OPTION ADDENDUM**

10-Dec-2020

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## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCZ245ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVCZ245ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVCZ245ANSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVCZ245APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVCZ245APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



www.ti.com 3-Jun-2022



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCZ245ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVCZ245ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVCZ245ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVCZ245APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LVCZ245APWT	TSSOP	PW	20	250	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

#### **TUBE**



#### \*All dimensions are nominal

	Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
١	SN74LVCZ245APW	PW	TSSOP	20	70	530	10.2	3600	3.5





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

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  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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